NPN Triple Diffused Planar Silicon Transistor



# 2SD2634

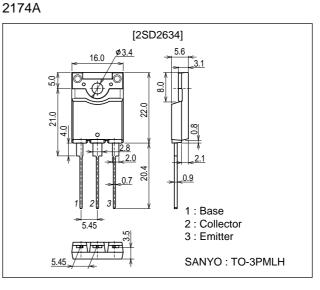
# Color TV Horizontal Deflection Output Applications

## Features

- High speed.
- High breakdown voltage(VCBO=1500V).
- High reliability(Adoption of HVP process).
- · Adoption of MBIT process.
- On-chip damper diode.

## **Package Dimensions**

unit : mm



## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		1500	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		8	А
Collector Current (Pulse)	ICP		20	А
Collector Dissipation	PC		3.0	W
		Tc=25°C	65	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =800V, I <sub>E</sub> =0			10	μΑ
Collector Cutoff Current	ICES	VCE=1500V, RBE=0			1.0	mA
Collector Sustain Voltage	VCEO(sus)	IC=100mA, IB=0	800			V
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0	40		130	mA

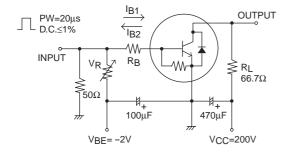
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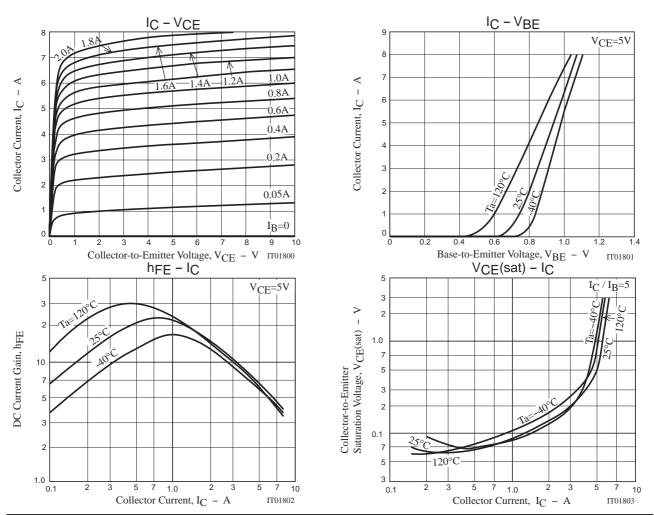
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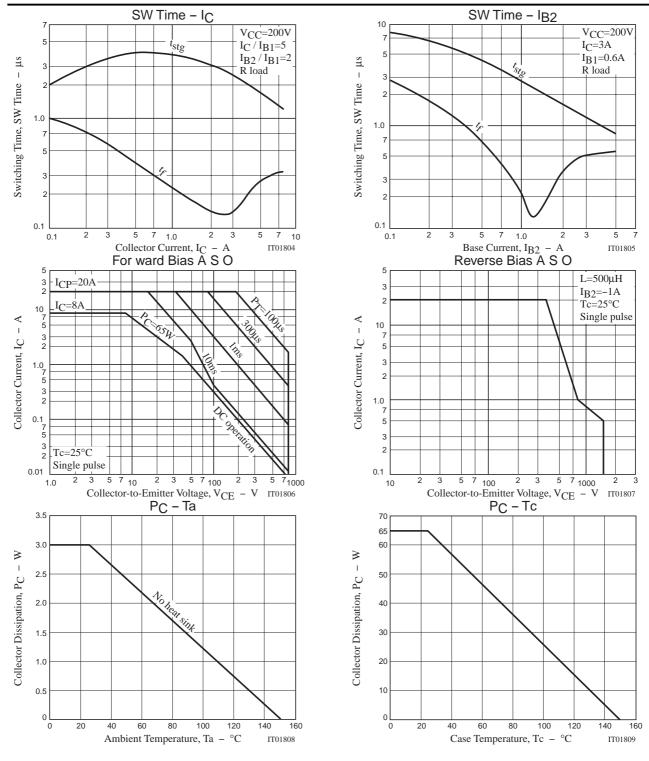
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	IC=4.5A, IB=0.9A			3	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	IC=4.5A, IB=0.9A			1.5	V
DC Current Gain	hFE1	VCE=5V, IC=1A	10			
	hFE2	V <sub>CE</sub> =5V, I <sub>C</sub> =5A	5		8	
Diode Forward Voltage	VF	IEC=7A			2	V
Fall Time	tf	IC=3A, IB1=0.6A, IB2=-1.2A			0.3	μs

### **Switching Time Test Circuit**







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